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Silicon PNP Epitaxial

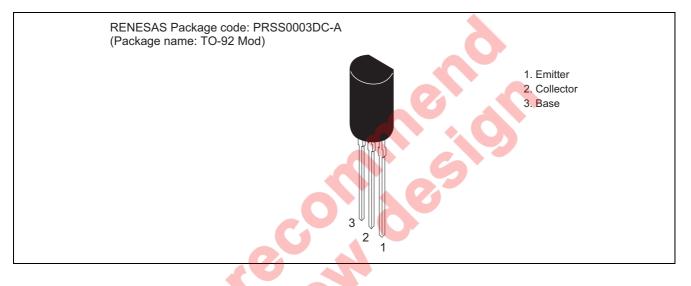
REJ03G0648-0200 (Previous ADE-208-1025) Rev.2.00 Aug.10.2005

### Application

### • Low frequency power amplifier

• Complementary pair with 2SD667/A

### Outline



# Absolute Maximum Ratings

|                              |                      |             |             | $(Ta = 25^{\circ}C)$ |
|------------------------------|----------------------|-------------|-------------|----------------------|
| Item                         | Symbol               | 2SB647      | 2SB647A     | Unit                 |
| Collector to base voltage    | V <sub>сво</sub>     | -120        | -120        | V                    |
| Collector to emitter voltage | V <sub>CEO</sub>     | -80         | -100        | V                    |
| Emitter to base voltage      | V <sub>EBO</sub>     | -5          | -5          | V                    |
| Collector current            | Ι <sub>C</sub>       | -1          | -1          | A                    |
| Collector peak current       | i <sub>C(peak)</sub> | -2          | -2          | A                    |
| Collector power dissipation  | Pc                   | 0.9         | 0.9         | W                    |
| Junction temperature         | Tj                   | 150         | 150         | °C                   |
| Storage temperature          | Tstg                 | -55 to +150 | -55 to +150 | °C                   |



# **Electrical Characteristics**

 $(Ta = 25^{\circ}C)$ 

|   |                                 |      | 2SB647 |      |      | 2SB647 <i>A</i> | 4    |      |   |
|---|---------------------------------|------|--------|------|------|-----------------|------|------|---|
| Item                                    | Symbol                          | Min  | Тур    | Max  | Min  | Тур             | Max  | Unit | Test conditions   |
| Collector to base<br>breakdown voltage  | V <sub>(BR)CBO</sub>            | -120 | —      | _    | -120 | —               | —    | V    | $I_{\rm C} = -10 \ \mu {\rm A}, \ I_{\rm E} = 0$                    |
| Collector to emitter breakdown voltage  | V <sub>(BR)CEO</sub>            | -80  | —      | _    | -100 | _               | _    | V    | $I_{C} = -1 \text{ mA}, \text{ R}_{BE} = \infty$                    |
| Emitter to base<br>breakdown voltage    | V <sub>(BR)EBO</sub>            | -5   | —      | _    | -5   | _               | _    | V    | $I_E = -10 \ \mu A, \ I_C = 0$                                      |
| Collector cutoff current                | I <sub>CBO</sub>                | _    | _      | -10  |      | _               | -10  | μΑ   | $V_{CB} = -100 \text{ V}, I_E = 0$                                  |
| DC current transfer ratio               | h <sub>FE1</sub> * <sup>1</sup> | 60   | —      | 320  | 60   | _               | 200  |      | $V_{CE} = -5 V,$<br>$I_{C} = -150 \text{ mA}^{*2}$                  |
|   | h <sub>FE2</sub>                | 30   | —      | _    | 30   | _               | _    |      | $V_{CE} = -5 V,$<br>$I_{C} = -500 \text{ mA}^{*2}$                  |
| Collector to emitter saturation voltage | V <sub>CE(sat)</sub>            |      | _      | -1   | —    |                 | -1   | V    | $I_{\rm C} = -500 \text{ mA},$<br>$I_{\rm B} = -50 \text{ mA}^{*2}$ |
| Base to emitter voltage                 | V <sub>BE</sub>                 | _    | —      | -1.5 | —    |                 | -1.5 | V    | $V_{CE} = -5 V,$<br>$I_{C} = -150 \text{ mA}^{*2}$                  |
| Gain bandwidth product                  | f <sub>T</sub>                  | _    | 140    | _    | -    | 140             | -    | MHz  | V <sub>CE</sub> = -5 V,<br>I <sub>C</sub> = -150 mA                 |
| Collector output<br>capacitance         | Cob                             | _    | 20     | _    | 3    | 20              |      | pF   | $V_{CB} = -10 \text{ V}, \text{ I}_{E} = 0$<br>f = 1 MHz            |

Notes: 1. The 2SB647 and 2SB647A are grouped by  $h_{FE1}$  as follows.

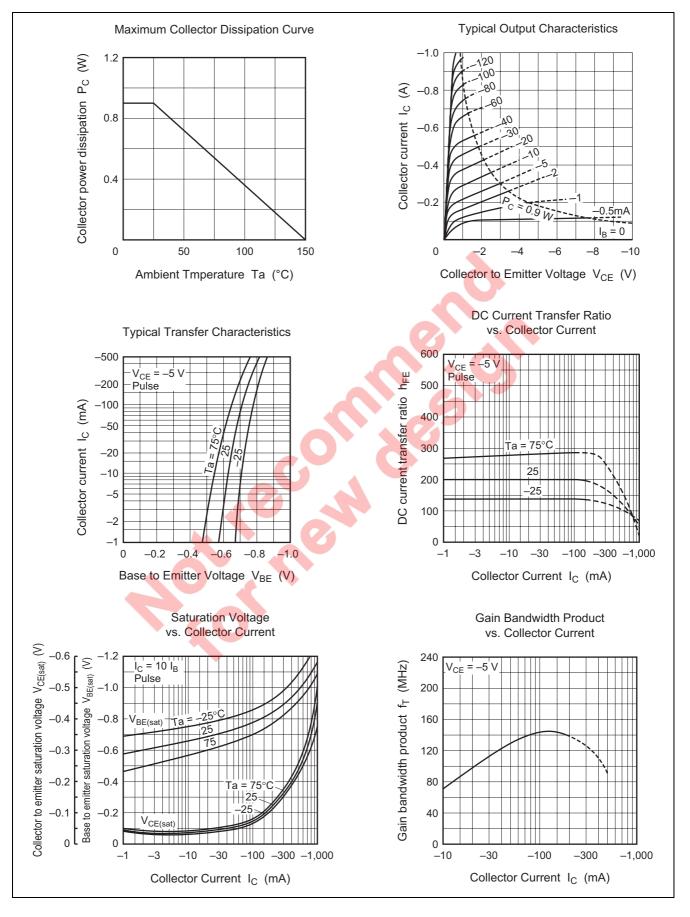
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Pulse test

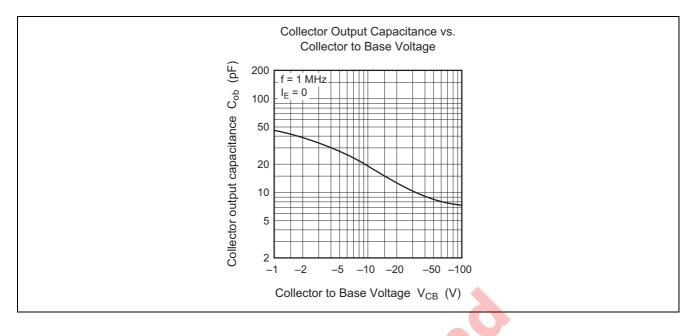
|         | В         | С          | D          |
|---------|-----------|------------|------------|
| 2SB647  |           | 100 to 200 | 160 to 320 |
| 2SB647A | 60 to 120 | 100 to 200 | -          |



### **Main Characteristics**

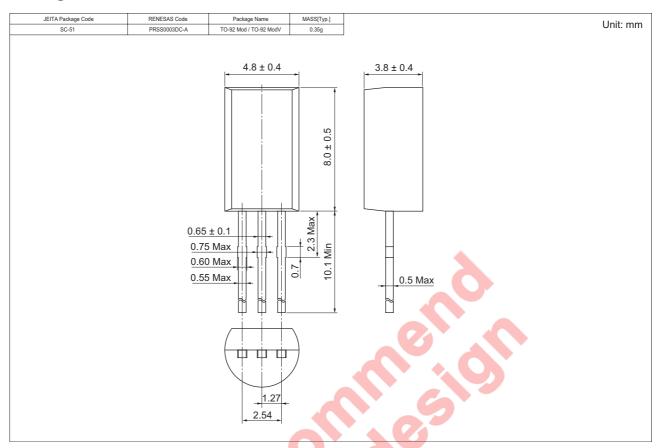








## **Package Dimensions**



## **Ordering Information**

| Part Name  | Quantity | Shipping Container      |
|--|----------|-------------------------|
| 2SB647CTZ-E<br>2SB647DTZ-E<br>2SB647ABTZ-E<br>2SB647ACTZ-E | 2500     | Hold Box, Radial Taping |

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